

## SCD5280

### Power Rectifier Diodes

#### GENERAL PURPOSE HIGH POWER RECTIFIER

##### Features:

- . All Diffused Structure
- . High Surge rating
- . Soft Reverse Recovery
- . Rugged Ceramic Hermetic Package
- . Pressure Assembled Device

##### Typical Applications:

- . Rectifier for Drives Applications
- . Medium voltage converters
- . Pulsed power applications
- . Crowbar Applications

#### ELECTRICAL CHARACTERISTICS AND RATINGS

##### Reverse Blocking

$V_{RRM}$ (1)	$V_{RSM}$ (1)
2400	2500

$V_{RRM}$  = Repetitive peak reverse voltage

$V_{RSM}$  = Non repetitive peak reverse voltage (2)

Repetitive peak reverse leakage	$I_{RRM}$	15 mA 75mA (3)
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##### Notes:

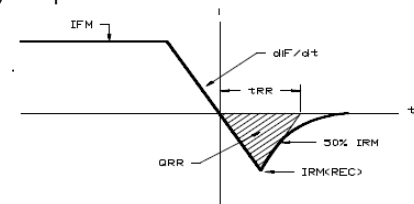
All ratings are specified for  $T_j=25^\circ\text{C}$  unless otherwise stated.

(1) All voltage ratings are specified for an applied 50Hz/60Hz sinusoidal waveform over the temperature range  $-40$  to  $+150^\circ\text{C}$ .

(2) 10 msec. max. pulse width

(3) Maximum value for  $T_j = 150^\circ\text{C}$ .

(4) See parameter definition below :



REVERSE RECOVERY CHARACTERISTIC

##### Conducting - on state

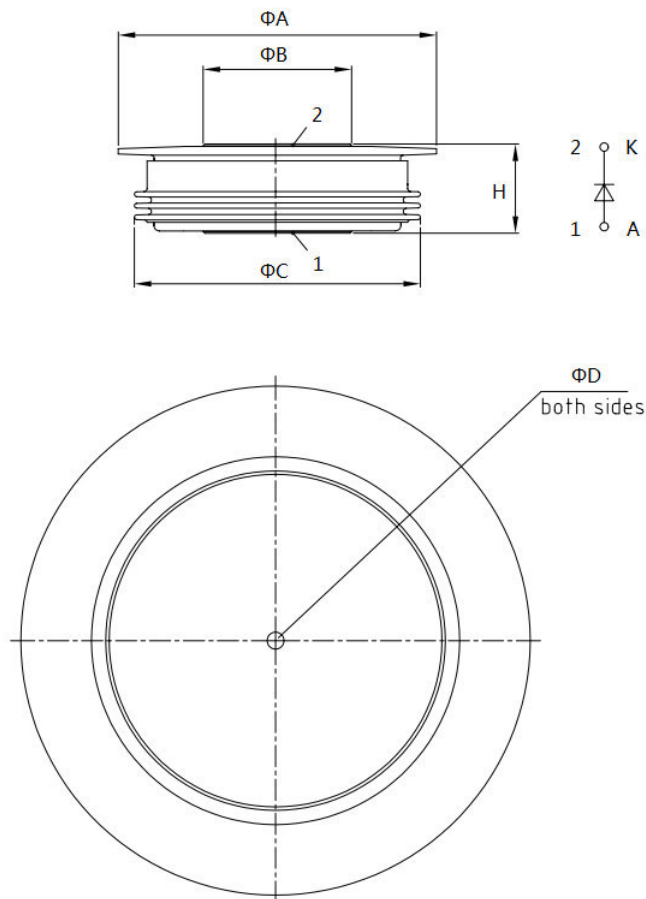
Parameter	Symbol	Min	Max.	Typ	Units	Conditions
Max. Average value of on-state current	$I_{F(AV)M}$		5282		A	Sinewave, 180° conduction, $T_c=55^\circ\text{C}$
RMS value of on-state current	$I_{F(RMS)M}$		9830		A	Nominal value
Peak one cycle surge (non repetitive) current	$I_{FSM}$		60		kA	$T_j=25^\circ\text{C}$ , $V_R=0,5V_{RRM}$ , $t_p=10\text{ms}$
I square t	$I^2t$		18000		$\text{kA}^2\text{s}$	10 msec
Peak on-state voltage	$V_F$		1.35		V	$I_F=6000\text{A}$ ; $T_j=160^\circ\text{C}$
Threshold voltage	$V_{FO}$		0.97		V	$T_j=160^\circ\text{C}$
Forward slope resistance	$r_F$		0.064		$\text{m}\Omega$	$T_j=160^\circ\text{C}$
Reverse Recovery Current (4)	$I_{RM(REC)}$		-		A	$I_{FM} = 1000\text{A}$ ; $dI_F/dt = 100\text{A}/\mu\text{s}$ , $T_j = T_j \text{ MAX.}$
Reverse Recovery Charge (4)	$Q_{rr}$		-		$\mu\text{C}$	
Reverse Recovery Time (4)	$t_{rr}$		-	-	$\mu\text{s}$	

\* For guaranteed maximum values, contact factory

**THERMAL AND MECHANICAL CHARACTERISTICS**

Parameter	Symbol	Min.	Max.	Typ.	Units	Conditions
Operating temperature	$T_j$	-55	+160		°C	
Storage temperature	$T_{stg}$	-55	+190		°C	
Thermal resistance - junction to case	$R_{\Theta(j-c)}$		0.011		K/W	Double side cooling Single sided cooled
Thermal resistance - case to sink	$R_{\Theta(c-s)}$		0.022		K/W	Double side cooling Single sided cooled
Thermal resistance - junction to sink	$R_{\Theta(j-s)}$		-		K/kW	Double side cooling Single sided cooled
Mounting force	P	27	47	-	kN	±20%
Weight	W			1.70	Kg	about

\* Mounting surfaces smooth, flat and greased

**CASE OUTLINE AND DIMENSIONS**


Sym	A	B	C	D	H
mm	109	73	98	3.5×3	26±1